

# KA79XX/KA79XXA

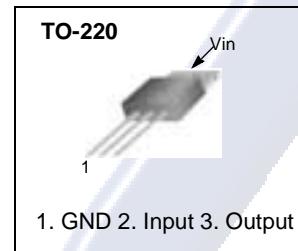
## 3-Terminal 1A Negative Voltage Regulator

### Features

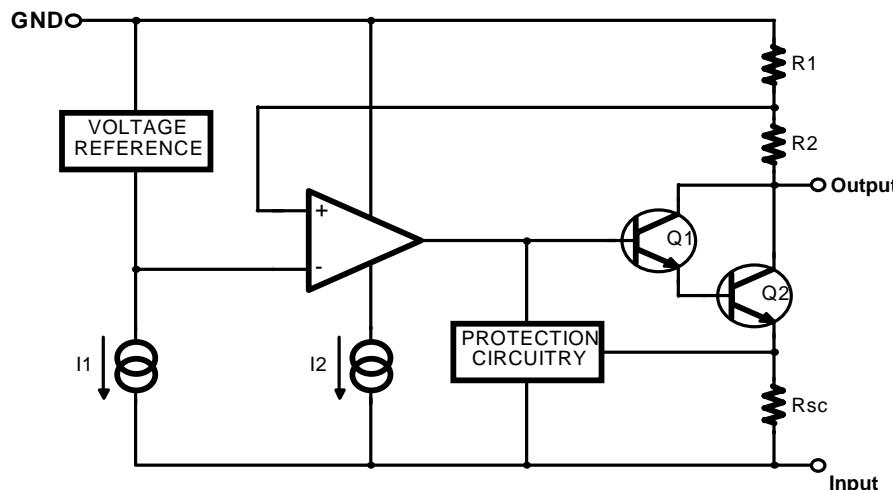
- Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -9, -10, -12, -15, -18 , -24V
- Internal Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area Compensation

### Description

The KA79XX/KA79XXA series of three-terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shutdown and safe operating area protection, making it essentially indestructible.



### Internal Block Diagram



KA79XX/KA79XXA

## Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage	V <sub>I</sub>	-35	V
Thermal Resistance Junction-Case (Note1)	R <sub>θJC</sub>	5	°C/W
Thermal Resistance Junction-Air (Note1, 2)	R <sub>θJA</sub>	65	°C/W
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	TSTG	- 65 ~ +150	°C

**Note:**

1. Thermal resistance test board  
Size: 76.2mm \* 114.3mm \* 1.6mm(1SOP)  
JEDEC standard: JESD51-3, JESD51-7
2. Assume no ambient airflow

## Electrical Characteristics (KA7905)

(V<sub>I</sub> = -10V, I<sub>O</sub> = 500mA, 0°C ≤ T<sub>J</sub> ≤ +125°C, C<sub>I</sub> = 2.2μF, C<sub>O</sub> = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit	
Output Voltage	V <sub>O</sub>	T <sub>J</sub> = +25°C		-4.8	-5.0	-5.2	V	
		I <sub>O</sub> = 5mA to 1A, P <sub>O</sub> ≤ 15W V <sub>I</sub> = -7V to -20V		-4.75	-5.0	-5.25		
Line Regulation (Note3)	ΔV <sub>O</sub>	T <sub>J</sub> = +25°C	V <sub>I</sub> = -7V to -25V	-	35	100	mV	
			V <sub>I</sub> = -8V to -12V	-	8	50		
Load Regulation (Note3)	ΔV <sub>O</sub>	T <sub>J</sub> = +25°C, I <sub>O</sub> = 5mA to 1.5A	V <sub>I</sub> = -7V to -25V		-	10	100	mV
			T <sub>J</sub> = +25°C, I <sub>O</sub> = 250mA to 750mA		-	3	50	
Quiescent Current	I <sub>Q</sub>	T <sub>J</sub> = +25°C		-	3	6	mA	
Quiescent Current Change	ΔI <sub>Q</sub>	I <sub>O</sub> = 5mA to 1A V <sub>I</sub> = -8V to -25V	V <sub>I</sub> = -8V to -25V		-	0.05	0.5	mA
			I <sub>O</sub> = 5mA to 1A V <sub>I</sub> = -8V to -25V		-	0.1	0.8	
Temperature Coefficient of V <sub>D</sub>	ΔV <sub>O</sub> /ΔT	I <sub>O</sub> = 5mA		-	-0.4	-	mV/°C	
Output Noise Voltage	V <sub>N</sub>	f = 10Hz to 100kHz, T <sub>A</sub> = +25°C		-	40	-	μV	
Ripple Rejection	RR	f = 120Hz, ΔV <sub>I</sub> = 10V		54	60	-	dB	
Dropout Voltage	V <sub>D</sub>	T <sub>J</sub> = +25°C, I <sub>O</sub> = 1A		-	2	-	V	
Short Circuit Current	I <sub>SC</sub>	T <sub>J</sub> = +25°C, V <sub>I</sub> = -35V		-	300	-	mA	
Peak Current	I <sub>PK</sub>	T <sub>J</sub> = +25°C		-	2.2	-	A	

**Note**

3. Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

**Electrical Characteristics (KA7906) (Continued)**

(VI = -11V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-5.75	-6	-6.25	V
		IO = 5mA to 1A, PO ≤ 15W VI = -9V to -21V		-5.7	-6	-6.3	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -8V to -25V	-	10	120	mV
			VI = -9V to -13V	-	5	60	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A		-	10	120	mV
		TJ = +25°C, IO = 250mA to 750mA		-	3	60	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -8V to -25V		-	0.1	1.3	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C		-	130	-	μV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

KA79XX/KA79XXA

**Electrical Characteristics (KA7908) (Continued)**

(VI = -14V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2µF, CO = 1µF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Output Voltage	VO	TJ = +25°C	-7.7	-8	-8.3	V	
		IO = 5mA to 1A, PO ≤ 15W VI = -10V to -23V	-7.6	-8	-8.4		
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -10.5V to -25V	-	10	160	mV
			VI = -11V to -17V	-	5	80	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A	-	12	160	mV	
			TJ = +25°C, IO = 250mA to 750mA	-	4	80	
Quiescent Current	IQ	TJ = +25°C	-	3	6	mA	
Quiescent Current Change	ΔIQ	IO = 5mA to 1A	-	0.05	0.5	mA	
		VI = -10.5V to -25V	-	0.1	1		
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA	-	-0.6	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C	-	175	-	µV	
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V	54	60	-	dB	
Dropout Voltage	VD	TJ = +25°C, IO = 1A	-	2	-	V	
Short Circuit Current	ISC	TJ = +25°C, VI = -35V	-	300	-	mA	
Peak Current	IPK	TJ = +25°C	-	2.2	-	A	

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

**Electrical Characteristics (KA7909) (Continued)**

(VI = -15V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2µF, CO = 1µF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-8.7	-9.0	-9.3	V
		IO = 5mA to 1A, PO ≤ 15W VI = -1.5V to -23V		-8.6	-9.0	-9.4	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -11.5V to -26V	-	10	180	mV
			VI = -12V to -18V	-	5	90	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A		-	12	180	mV
		TJ = +25°C, IO = 250mA to 750mA		-	4	90	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -11.5V to -26V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-0.6	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C		-	175	-	µV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

KA79XX/KA79XXA

**Electrical Characteristics (KA7910) (Continued)**

(VI = -17V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Output Voltage	VO	TJ = +25°C	-9.6	-10	-10.4	V	
		IO = 5mA to 1A, PO ≤ 15W VI = -12V to -28	-9.5	-10	-10.5		
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -12.5V to -28V	-	12	200	mV
			VI = -14V to -20V	-	6	100	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A	-	12	200	mV	
		TJ = +25°C, IO = 250mA to 750mA	-	4	100		
Quiescent Current	IQ	TJ = +25°C	-	3	6	mA	
Quiescent Current Change	ΔIQ	IO = 5mA to 1A	-	0.05	0.5	mA	
		VI = -12.5 to -28V	-	0.1	1		
Temperature Coefficient of VO	ΔVo/ΔT	IO = 5mA	-	-1	-	mV/°C	
Output Noise Voltage	VN	10Hz ≤ f ≤ 100kHz, TA = +25°C	-	280	-	μV	
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V	54	60	-	dB	
Dropout Voltage	VD	TJ = +25°C, IO = 1A	-	2	-	V	
Short Circuit Current	ISC	TJ = +25°C, VI = -35V	-	300	-	mA	
Peak Current	IPK	TJ = +25°C	-	2.2	-	A	

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

## Electrical Characteristics (KA7912) (Continued)

( $V_I = -19V$ ,  $I_O = 500mA$ ,  $0^\circ C \leq T_J \leq +125^\circ C$ ,  $C_I = 2.2\mu F$ ,  $C_O = 1\mu F$ , unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	$V_O$	$T_J = +25^\circ C$		-11.5	-12	-12.5	V
		$I_O = 5mA$ to $1A$ , $P_O \leq 15W$ $V_I = -15.5V$ to $-27V$		-11.4	-12	-12.6	
Line Regulation (Note1)	$\Delta V_O$	$T_J = +25^\circ C$	$V_I = -14.5V$ to $-30V$	-	12	240	mV
			$V_I = -16V$ to $-22V$	-	6	120	
Load Regulation (Note1)	$\Delta V_O$	$T_J = +25^\circ C$ , $I_O = 5mA$ to $1.5A$		-	12	240	mV
		$T_J = +25^\circ C$ , $I_O = 250mA$ to $750mA$		-	4	120	
Quiescent Current	$I_Q$	$T_J = +25^\circ C$		-	3	6	mA
Quiescent Current Change	$\Delta I_Q$	$I_O = 5mA$ to $1A$		-	0.05	0.5	mA
		$V_I = -14.5V$ to $-30V$		-	0.1	1	
Temperature Coefficient of $V_D$	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-0.8	-	mV/ $^\circ C$
Output Noise Voltage	$V_N$	$f = 10Hz$ to $100kHz$ , $T_A = +25^\circ C$		-	200	-	$\mu V$
Ripple Rejection	$RR$	$f = 120Hz$ , $\Delta V_I = 10V$		54	60	-	dB
Dropout Voltage	$V_D$	$T_J = +25^\circ C$ , $I_O = 1A$		-	2	-	V
Short Circuit Current	$I_{SC}$	$T_J = +25^\circ C$ , $V_I = -35V$		-	300	-	mA
Peak Current	$I_{PK}$	$T_J = +25^\circ C$		-	2.2	-	A

### Note

1. Load and line regulation are specified at constant junction temperature. Changes in  $V_O$  due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

KA79XX/KA79XXA

**Electrical Characteristics (KA7915) (Continued)**

(VI = -23V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-14.4	-15	-15.6	V
		IO = 5mA to 1A, PO ≤ 15W VI = -18V to -30V		-14.25	-15	-15.75	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -17.5V to -30V	-	12	300	mV
			VI = -20V to -26V	-	6	150	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A		-	12	300	mV
		TJ = +25°C, IO = 250mA to 750mA		-	4	150	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -17.5V to -30V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C		-	250	-	μV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

**Electrical Characteristics (KA7918) (Continued)**

(VI = -27V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2µF, CO = 1µF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-17.3	-18	-18.7	V
		IO = 5mA to 1A, PO ≤ 15W VI = -22.5V to -33V		-17.1	-18	-18.9	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -21V to -33V	-	15	360	mV
			VI = -24V to -30V	-	8	180	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A		-	15	360	mV
		TJ = +25°C, IO = 250mA to 750mA		-	5	180	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -21V to -33V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C		-	300	-	µV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

KA79XX/KA79XXA

**Electrical Characteristics (KA7924) (Continued)**

(VI = -33V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-23	-24	-25	V
		IO = 5mA to 1A, PO ≤ 15W VI = -27V to -38V		-22.8	-24	-25.2	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -27V to -38V	-	15	480	mV
			VI = -30V to -36V	-	8	180	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A		-	15	480	mV
		TJ = +25°C, IO = 250mA to 750mA		-	5	240	
Quiescent Current	IQ	TJ = +25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -27V to -38V		-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C		-	400	-	µV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

**Electrical Characteristics (KA7905A) (Continued)**

(VI = -10V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C	-4.9	-5.0	-5.1	V
		IO = 5mA to 1A, PO ≤ 15W VI = -7V to -20V	-4.8	-5.0	-5.2	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -7V to -20V IO = 1A	-	5	50
			VI = -8V to -12V IO = 1A	-	2	25
		VI = -7.5V to -25V	-	7	50	mV
		VI = -8V to -12V, IO=1A	-	7	50	
Load Regulation (Note1)	ΔVO	IO = 5mA to 1.5A TJ = +25°C	-	10	100	mV
		TJ = +25°C, IO = 250mA to 750mA	-	3	50	
Quiescent Current	IQ	TJ = +25°C	-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A	-	0.05	0.5	mA
		VI = -8V to -25V	-	0.1	0.8	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA	-	-0.4	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C	-	40	-	μV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V	54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A	-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V	-	300	-	mA
Peak Current	IPK	TJ = +25°C	-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

KA79XX/KA79XXA

**Electrical Characteristics (KA7912A) (Continued)**

(VI = -19V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C	-11.75	-12	-12.25	V
		IO = 5mA to 1A, PO ≤ 15W VI = -15.5V to -27V	-11.5	-12	-12.5	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -14.5V to -27V IO = 1A	-	12	120
			VI = -16V to -22V IO = 1A	-	6	60
		VI = -14.8V to -30V	-	12	120	mV
		VI = -16V to -22V, IO = 1A	-	12	120	
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A	-	12	150	mV
		TJ = +25°C, IO = 250mA to 750mA	-	4	75	
Quiescent Current	IQ	TJ = +25°C	-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A	-	0.05	0.5	mA
		VI = -15V to -30V	-	0.1	1	
Temperature Coefficient of VD	ΔVO/ΔT	IO = 5mA	-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C	-	200	-	μV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V	54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A	-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V	-	300	-	mA
Peak Current	IPK	TJ = +25°C	-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

*Electrónica S.A. de C.V.*

**Electrical Characteristics (KA7915A) (Continued)**

(VI = -23V, IO = 500mA, 0°C ≤ TJ ≤ +125°C, CI = 2.2μF, CO = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C	-14.7	-15	-15.3	V
		IO = 5mA to 1A, PO ≤ 15W VI = -18V to -30V	-14.4	-15	-15.6	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -17.5V to -30V IO = 1A	-	12	150
			VI = -20V to -26V IO = 1A	-	6	75
		VI = -17.9V to -30V	-	12	150	mV
			VI = -20V to -26V, IO = 1A	-	6	150
Load Regulation (Note1)	ΔVO	TJ = +25°C, IO = 5mA to 1.5A	-	12	150	mV
		TJ = +25°C, IO = 250mA to 750mA	-	4	75	
Quiescent Current	IQ	TJ = +25°C	-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A	-	0.05	0.5	mA
		VI = -18.5V to -30V	-	0.1	1	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA	-	-0.9	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz, TA = +25°C	-	250	-	µV
Ripple Rejection	RR	f = 120Hz, ΔVI = 10V	54	60	-	dB
Dropout Voltage	VD	TJ = +25°C, IO = 1A	-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V	-	300	-	mA
Peak Current	IPK	TJ = +25°C	-	2.2	-	A

**Note**

1. Load and line regulation are specified at constant junction temperature. Changes in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

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## Typical Performance Characteristics

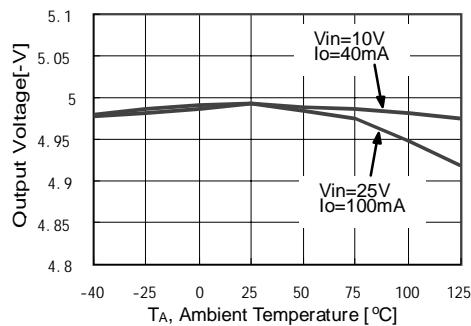


Figure 1. Output Voltage

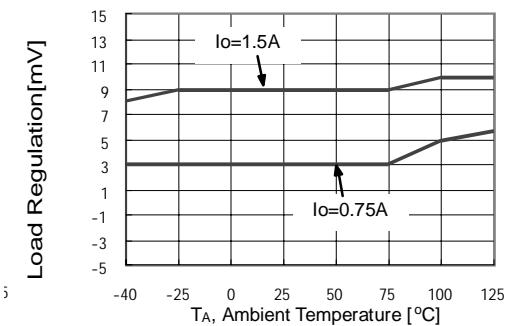


Figure 2. Load Regulation

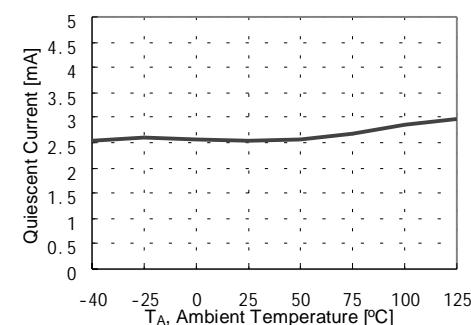


Figure 3. Quiescent Current

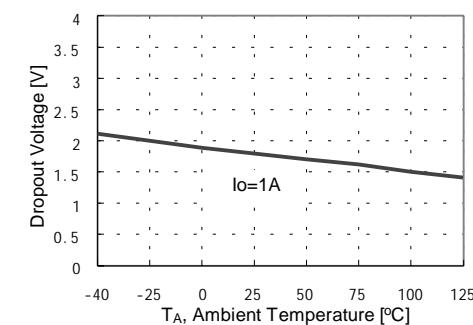


Figure 4. Dropout Voltage

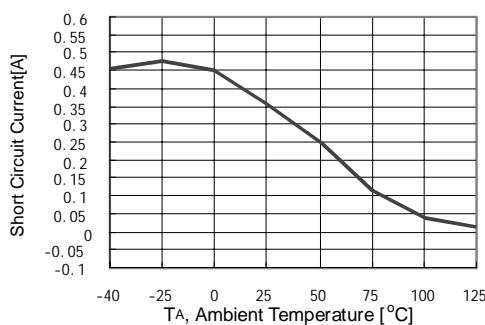


Figure 5. Short Circuit Current

## Typical Applications

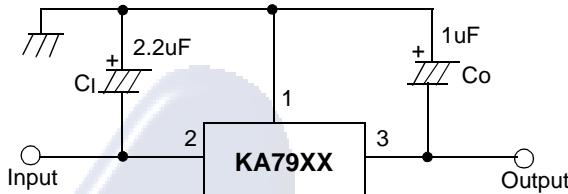


Figure 6. Negative Fixed output regulator

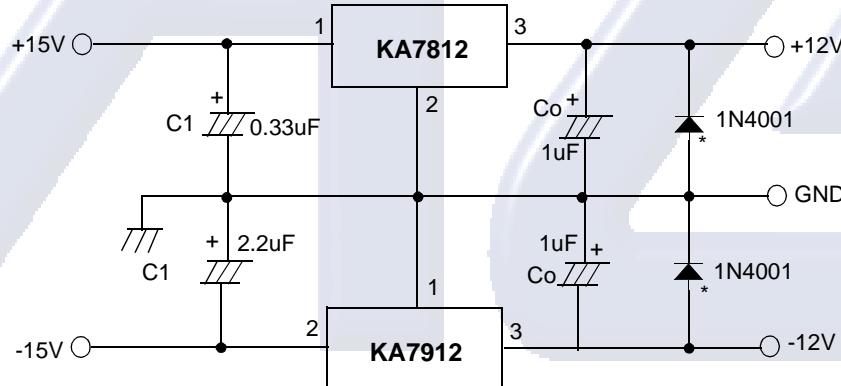


Figure 7. Split power supply ( ± 12V/1A)

**Note:**

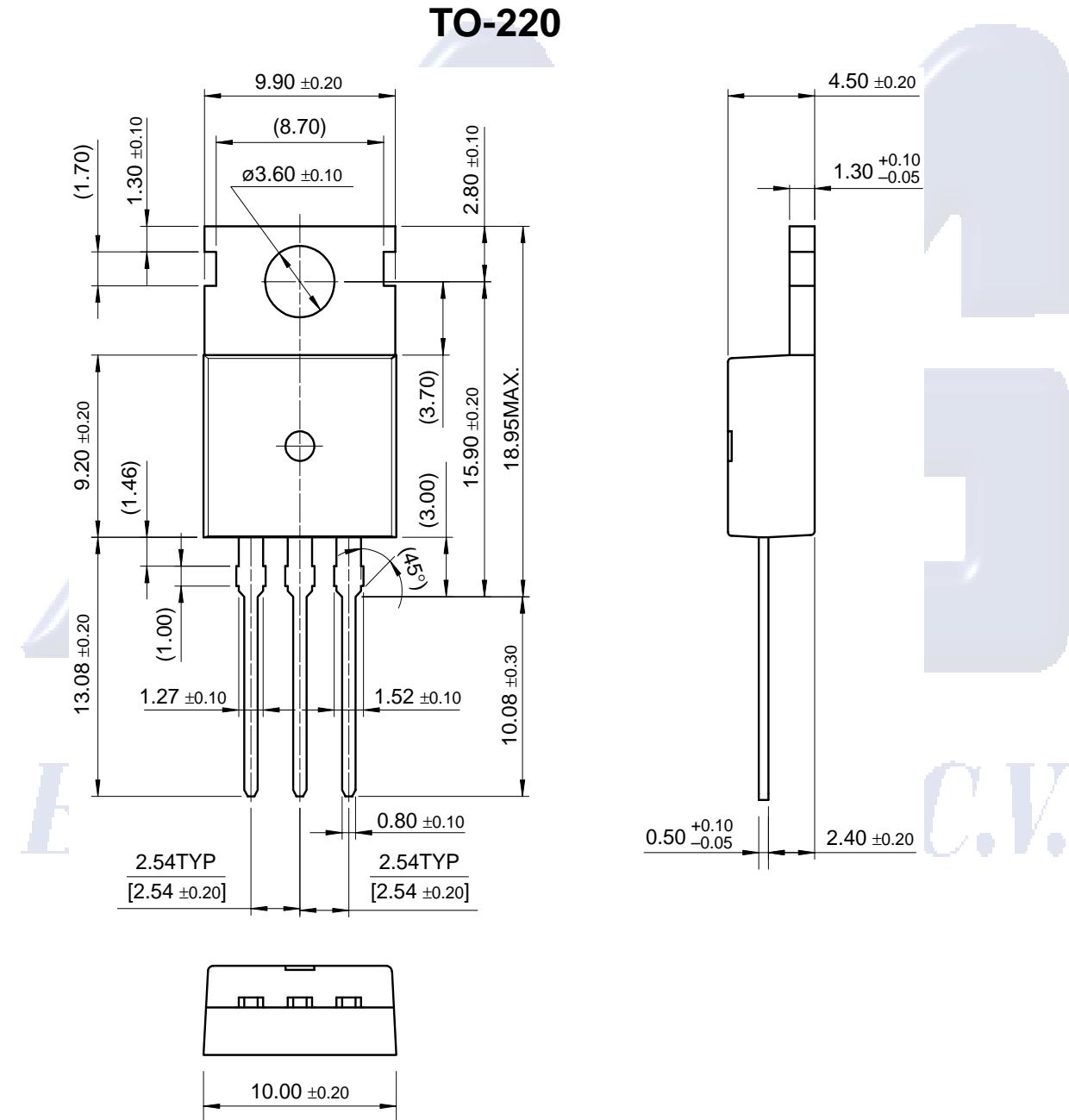
- (1) To specify an output voltage, substitute voltage value for "XX"
- (2) Required for stability. For value given, capacitor must be solid tantalum. If aluminium electronics are used, at least ten times value shown should be selected. C1 is required if regulator is located an appreciable distance from power supply filter.
- (3) To improve transient response. If large capacitors are used, a high current diode from input to output (1N4001 or similar) should be introduced to protect the device from momentary input short circuit.

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## Mechanical Dimensions

### Package

**Dimensions in millimeters**



## Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature
KA7905	$\pm 4\%$	TO-220	$0 \sim +125^{\circ}\text{C}$
KA7906			
KA7908			
KA7909			
KA7910			
KA7912			
KA7915			
KA7918			
KA7924			
KA7905A			
KA7912A			
KA7915A			

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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